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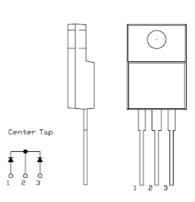
## MBRF10100CTP SCHOTTKY RECTIFIER

#### **Applications:**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

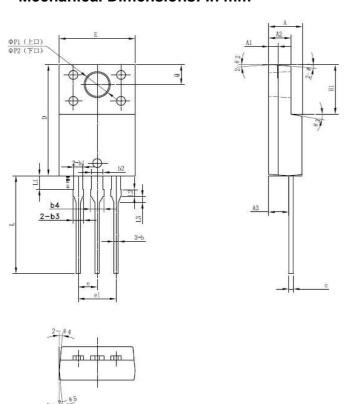
#### Features:

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request



**OUTLINE DRAWING** 

#### **Mechanical Dimensions: In mm**



SYMBOL	MIN.	TYP.	MAX.
Α	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.80	3.00	3.20
A2 A3 b	2.50	3.00 2.70	2.90
b	0.50	0.60	0.75
b1	1.10	1.20	1.35
b2	1.50	1.60	1.75
b3	1.20	1.30	1.45
b4	1.60	1.70	1.85
	0.55	0.60	0.75
C D E	14.80	15.00	15.20
Е	9.96	10.16	10.36
е		2.55	
e1		5.10	
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60	1.80	2.00
L2	0.80	1.00	1.20
L3	0.60	0.80	1.00
ΦP1(上口)	3.30	3.50	3.70
ΦP2(下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
Θ1		5°	
Θ2		4°	
Θ3		10°	
Θ4		5°	
Θ5		5°	

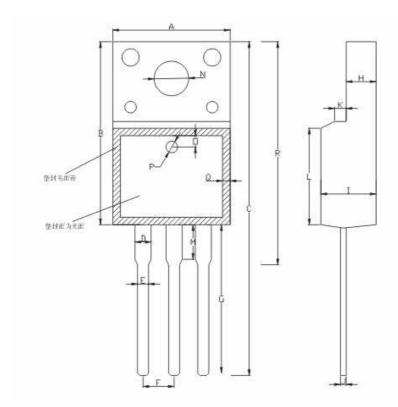
### **OPTION 1(HD)**

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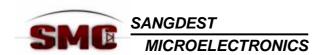
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A:10.20	$\pm 0.50$	B:15.90	$\pm0.50$	C:29.00	$\pm1.00$	D:1.24	$\pm0.10$
E:0.80	$\pm 0.10$	F:2.54	$\pm 0.10$	G:13.10	$\pm 1,0$	H:2.55	$\pm 0.05$
I:4.70	$\pm 0.05$	J:0.50	$\pm 0.05$	K:1.20	$\pm 0.20$	L:8.00	$\pm 0.50$
M:3.00	$\pm 0.50$	N:3.20	$\pm 0.20$	O:1,25	$\pm 0.05$	P:1.5	$\pm 0.05$
Q:1.0	±0.20	R:19.2	±1.0				

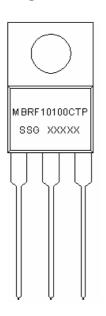
**OPTION 2(SR)** 

**ITO-220AB** 



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## **Marking Diagram:**



Where XXXXX is YYWWL

MBR = Device Type F = Package type

10 = Forward Current (10A) 100 = Reverse Voltage (100V)

CTP = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

## **Ordering Information:**

Device	Package	Shipping
MBRF10100CTP	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	100	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =105℃, rectangular wave form	10	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	120	А

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#### **Electrical Characteristics:**

Characteristics	_Symbol_	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 5A, Pulse, T <sub>J</sub> = 25 °C	0.85	V
(per leg) *	$V_{F2}$	@ 5A, Pulse, T <sub>J</sub> = 125 °C	0.75	V
Max. Reverse Current at DC condition (per leg)	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}C$	1.0	mA
Max. Reverse Current (per leg) *	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125  ^{\circ}\text{C}$	15	mA
Max. Junction Capacitance (per leg)	C <sub>T</sub>	$@V_R = 5V, T_C = 25  ^{\circ}C$ $f_{SIG} = 1MHz$	300	pF
Typical Series Inductance (per leg)	Ls	Measured lead to lead 5 mm from package body	8.0	nΗ
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs
RSM Isolation Voltage (t = 1.0 second, R. H. $<$ =30%, $T_A$ = 25 °C)	$V_{ISO}$	Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	4500	V
		Clip mounting, the epoxy body is inside the heatsink.	3500	V
		Screw mounting, the epoxy body is inside the heatsink.	1500	

<sup>\*</sup> Pulse Width < 300 $\mu$ s, Duty Cycle <2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	<b>Specification</b>	Units	
Max. Junction Temperature	$T_J$	-	-55 to +150	ç	
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C	
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ heta JC}$	DC operation	4.5	°C/W	
Approximate Weight	wt	-	2	g	
Case Style	ITO-220AB				

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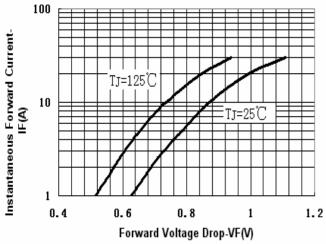


Fig.1-Typical Forward Voltage Drop Characteristics

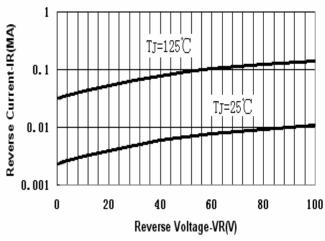


Fig.2-Typical Values Of Reverse Current Vs.Reverse Voltage

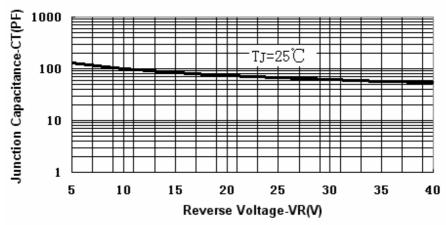


Fig.3-Typical Junction Capacitance Vs.Reverse Voltage

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#### MBRF10100CTP

Technical Data
Data Sheet N0077, Rev. -

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